



ZXTP25140BFHQ

140V PNP MEDIUM POWER TRANSISTOR IN SOT23

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

- BV_{CEO} > -140V
- BV_{ECO} > -7V
- I_C = -1A Continuous Collector Current
- V_{CE(sat)} < -260mV @ -1A
- R_{CE(sat)} = 180mΩ
- High Power Dissipation SOT23
- 180V Forward Blocking Voltage
- Low Saturation Voltage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

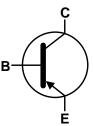
Applications

- DC-DC Converters
- High Side Switching

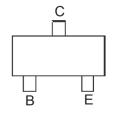
SOT23



Top View



Device Symbol



Top View Pin-Out

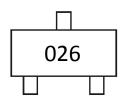
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25140BFHQTA	Automotive	026	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



026 = Product Type Marking Code

ZXTP25140BFHQ Document Number: DS38587 Rev. 1 - 2 1 of

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage (Forward Blocking)	V _{CEX}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-collector voltage (Reverse Blocking)	V _{ECO}	-7	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 5)	Ic	-1	Α
Peak Pulse Current	I _{CM}	-3	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation Linear derating factor	(Note 6)		0.73 5.84		
	(Note 7)		1.05 8.4	10/	
	(Note 8)	P _D	1.25 9.6	W	
	(Note 9)] [1.81 14.5		
Thermal Resistance, Junction to Ambient	(Note 6) (Note 7)	_	171 119		
	(Note 8) (Note 9)	$R_{\theta JA}$	100 69	°C/W	
Thermal Resistance, Junction to Lead	(Note 10)	$R_{ heta JL}$	74.95	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

Notes:

- 6. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 7. Same as note (4), except the device is surface mounted on 25mm x 25mm with 2 oz copper.
- 8. Same as note (4), except the device is surface mounted on $50 \text{mm} \times 50 \text{mm}$ with 2 oz copper.
- 9. Same as note (6), except the device is measured at t<5secs.
- 10. Thermal resistance from junction to solder-point (at the end of the collector lead).

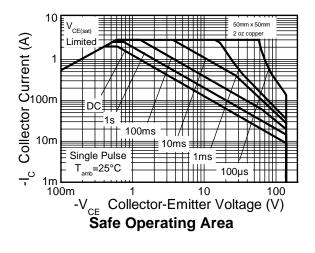
ESD Ratings (Note 11)

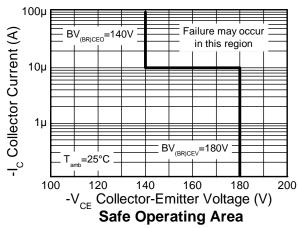
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

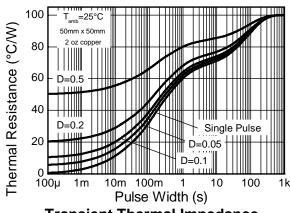
Notes: 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

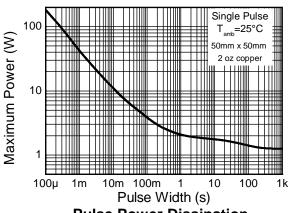


Thermal Characteristics and Derating Information



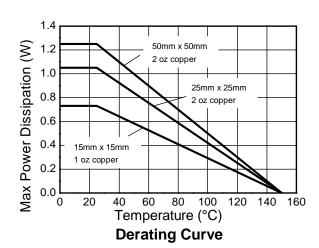






Transient Thermal Impedance

Pulse Power Dissipation





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-180	-205	-	V	$I_C = -100 \mu A$
						I _C = -100μA
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV _{CEX}	-180	-205	-	V	$R_{BE} \leq 1k\Omega$ or
						-0.25V < V _{BE} < 1V
Collector-Emitter Breakdown Voltage (Base Open) (Note 12)	BV _{CEO}	-140	-160	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	I _E = -100μA
Emitter-Base Breakdown Voltage (Reverse Blocking) (Note 12)	BV _{ECO}	-7	-8.5	-	V	I _E = -100μA
Collector-Base Cutoff Current	1	i	< -1	-50	nA	V _{CB} = -144V
Collector-base Cuton Current	I _{CBO}	i	•	-20	μΑ	$V_{CB} = -144V$, $T_{amb} = +100$ °C
						V _{CE} = -144V;
Collector-Emitter Cutoff Current	ICEX		-	-100	nA	$R_{BE} \leq 1k\Omega$ or
						-0.25V < V _{BE} < 1V
Emitter-Base Cutoff Current	I _{EBO}	-	< -1	-50	nA	$V_{EB} = -5.6V$
		100	200	300		$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 12)	h _{FE}	100	190	-	-	$I_C = -0.1A$, $V_{CE} = -2V$
		20	30	-		$I_C = -1A$, $V_{CE} = -2V$
		-	-40	-50		$I_C = -0.1A$, $I_B = -10mA$
		-	-110	-135		$I_C = -0.1A$, $I_B = -2mA$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(sat)}	-	-90	-110	mV	$I_C = -0.5A$, $I_B = -50mA$
			-170	-230		$I_C = -0.5A$, $I_B = -25mA$
		-	-180	-260		$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 12)	V _{BE(sat)}	-	-850	-950	mV	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 12)	V _{BE(on)}	-	-800	-900	mV	$I_C = -1A$, $V_{CE} = -2V$
Output Capacitance	C _{obo}	-	10	-	pF	$V_{CB} = -20V$, $f = 1MHz$
Transition Frequency	f⊤	-	75	-	MHz	$V_{CE} = -20V$, $I_{C} = -10mA$, $f = 20MHz$
Turn-on time	t _{on}	-	102	-	ns	$V_{CC} = -20V, I_{C} = -100mA,$
Turn-off time	t _{off}	•	854	-	ns	$I_{B1} = I_{B2} = -10 \text{mA}$

Notes: 12. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

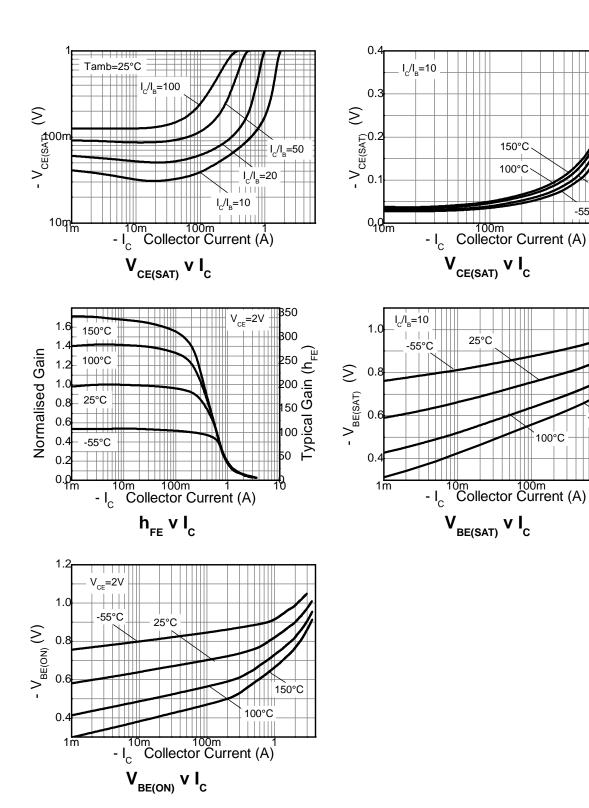
25°C

150°C

-55°C



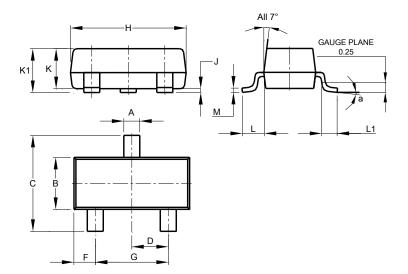
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

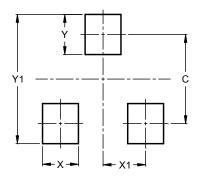
Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.0		



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